

Voltage Detector IC Series for Automotive

Free Delay Time Setting

CMOS Voltage Detector IC Series

BD52Exxx-M series BD53Exxx-M series

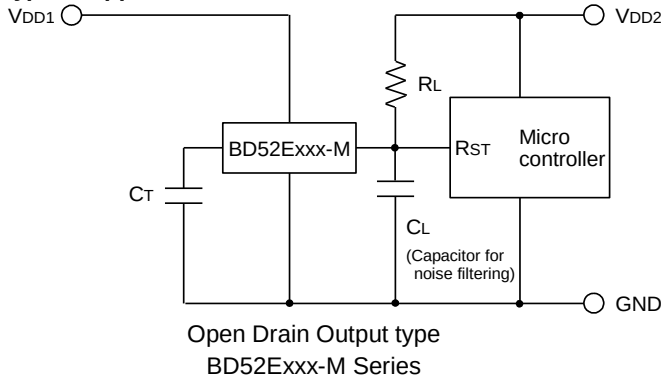
General Description

Rohm's BD52Exxx and BD53Exxx series are highly accurate, low current consumption Voltage Detector ICs with a capacitor controlled time delay. The line up includes BD52Exxx devices with N-channel open drain output and BD53Exxx devices with CMOS output. The devices are available for specific detection voltages ranging from 2.3V to 6.0V in increments of 0.1V.

Features

- Delay Time Controlled by external Capacitor
- Two output types(N-channel open drain and CMOS output)
- Ultra-low current consumption
- Very small, lightweight and thin package
- Package SSOP5 is similar to SOT-23-5(JEDEC)
- AEC-Q100 Qualified

Typical Application Circuit



Key Specifications

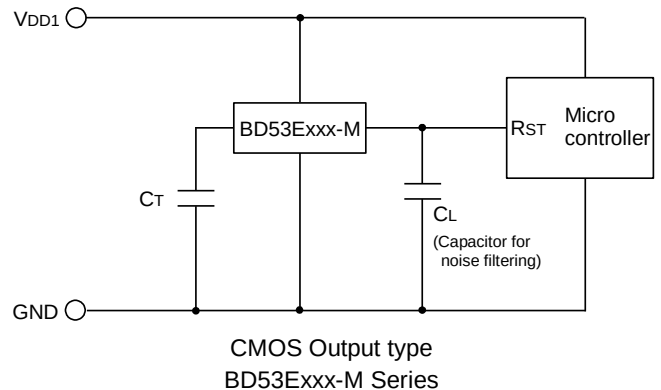
- Detection voltage: 2.3V to 6.0V (Typ.)
0.1V steps
- High accuracy detection voltage: $\pm 1.0\%$
- Ultra-low current consumption: 0.95 μ A (Typ.)

Package

 SSOP5:  2.90mm x 2.80mm x 1.25mm

Applications

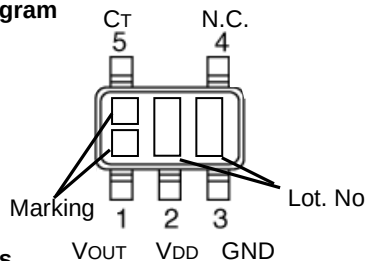
Circuits using microcontrollers or logic circuits that require a reset for automotive applications (car navigation, car audio, meter panel, exterior lamp etc.)



Connection Diagram

SSOP5

TOP VIEW



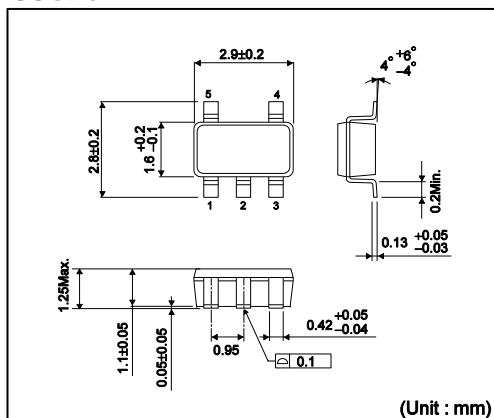
Pin Descriptions

SSOP5		
PIN No.	Symbol	Function
1	VOUT	Reset Output
2	VDD	Power Supply Voltage
3	GND	GND
4	N.C.	Unconnected Terminal
5	C _T	Capacitor connection terminal for output delay time

●Ordering Information

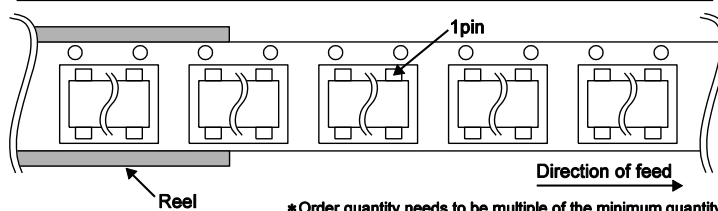
Ordering information													
B D x x E x x x								—	M T R				
Part Number		Output Type 52 : Open Drain 53 : CMOS			Reset Voltage Value 23 : 2.3V ↓ 0.1V step 60 : 6.0V			Package G : SSOP5		Product Category M : Automotive Category		Packaging and forming specification TR : Embossed tape and reel	

SSOP5



<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand)



●Lineup

Output Type	Open Drain		CMOS	
Detection Voltage	Marking	Part Number	Marking	Part Number
6.0V	Ph	BD52E60	Ud	BD53E60
5.9V	Pg	BD52E59	Uc	BD53E59
5.8V	Pf	BD52E58	Ub	BD53E58
5.7V	Pe	BD52E57	Ua	BD53E57
5.6V	Pd	BD52E56	Ry	BD53E56
5.5V	Pc	BD52E55	Rr	BD53E55
5.4V	Pb	BD52E54	Rp	BD53E54
5.3V	Pa	BD52E53	Rn	BD53E53
5.2V	Ny	BD52E52	Rm	BD53E52
5.1V	Nr	BD52E51	Rk	BD53E51
5.0V	Np	BD52E50	Rh	BD53E50
4.9V	Nn	BD52E49	Rg	BD53E49
4.8V	Nm	BD52E48	Rf	BD53E48
4.7V	Nk	BD52E47	Re	BD53E47
4.6V	Nh	BD52E46	Rd	BD53E46
4.5V	Ng	BD52E45	Rc	BD53E45
4.4V	Nf	BD52E44	Rb	BD53E44
4.3V	Ne	BD52E43	Ra	BD53E43
4.2V	Nd	BD52E42	Qy	BD53E42
4.1V	Nc	BD52E41	Qr	BD53E41
4.0V	Nb	BD52E40	Qp	BD53E40
3.9V	Na	BD52E39	Qn	BD53E39
3.8V	My	BD52E38	Qm	BD53E38
3.7V	Mr	BD52E37	Qk	BD53E37
3.6V	Mp	BD52E36	Qh	BD53E36
3.5V	Mn	BD52E35	Qg	BD53E35
3.4V	Mm	BD52E34	Qf	BD53E34
3.3V	Mk	BD52E33	Qe	BD53E33
3.2V	Mh	BD52E32	Qd	BD53E32
3.1V	Mg	BD52E31	Qc	BD53E31
3.0V	Mf	BD52E30	Qb	BD53E30
2.9V	Me	BD52E29	Qa	BD53E29
2.8V	Md	BD52E28	Py	BD53E28
2.7V	Mc	BD52E27	Pr	BD53E27
2.6V	Mb	BD52E26	Pp	BD53E26
2.5V	Ma	BD52E25	Pn	BD53E25
2.4V	Ly	BD52E24	Pm	BD53E24
2.3V	Lr	BD52E23	Pk	BD53E23

●Absolute maximum ratings

Parameter		Symbol	Limits	Unit
Power Supply Voltage		V_{DD-GND}	-0.3 to +10	V
Output Voltage	Nch Open Drain Output	V_{OUT}	GND-0.3 to +10	V
	CMOS Output		GND-0.3 to $V_{DD}+0.3$	
Output Current		I_o	80	V
Power Dissipation	SSOP5 *1*2	P_d	540	mW
Operating Temperature		T_{opr}	-40 to +105	°C
Ambient Storage Temperature		T_{stg}	-55 to +125	°C

*1 Reduced by 5.4mW/°C when used over 25°C.

*2 When mounted on ROHM standard circuit board (70mm×70mm×1.6mm, glass epoxy board).

●Electrical characteristics (Unless Otherwise Specified $T_a=-40$ to 105°C)

Parameter	Symbol	Condition		Limit			Unit
				Min.	Typ.	Max.	
Detection Voltage	V_{DET}	$V_{DD}=H \rightarrow L, R_L=470k\Omega$ *1		$V_{DET}(T) \times 0.99$	$V_{DET}(T)$	$V_{DET}(T) \times 1.01$	V
		$V_{DET}=2.5V$	$T_a=+25^{\circ}\text{C}$	2.475	2.5	2.525	
			$T_a=-40^{\circ}\text{C}$ to 85°C	2.418	-	2.584	
			$T_a=85^{\circ}\text{C}$ to 105°C	2.404	-	2.597	
		$V_{DET}=3.0V$	$T_a=+25^{\circ}\text{C}$	2.970	3.0	3.030	
			$T_a=-40^{\circ}\text{C}$ to 85°C	2.901	-	3.100	
			$T_a=85^{\circ}\text{C}$ to 105°C	2.885	-	3.117	
		$V_{DET}=3.3V$	$T_a=+25^{\circ}\text{C}$	3.267	3.3	3.333	
			$T_a=-40^{\circ}\text{C}$ to 85°C	3.191	-	3.410	
			$T_a=85^{\circ}\text{C}$ to 105°C	3.173	-	3.428	
		$V_{DET}=4.2V$	$T_a=+25^{\circ}\text{C}$	4.158	4.2	4.242	
			$T_a=-40^{\circ}\text{C}$ to 85°C	4.061	-	4.341	
			$T_a=85^{\circ}\text{C}$ to 105°C	4.039	-	4.364	
Circuit Current when ON	I_{DD1}	$V_{DD}=V_{DET}-0.2V$	$V_{DET}=2.3-3.1V$	-	0.80	2.40	μA
			$V_{DET}=3.2-4.2V$	-	0.85	2.55	
			$V_{DET}=4.3-5.2V$	-	0.90	2.70	
			$V_{DET}=5.3-6.0V$	-	0.95	2.85	
Circuit Current when OFF	I_{DD2}	$V_{DD}=V_{DET}+2.0V$	$V_{DET}=2.3-3.1V$	-	0.75	2.25	μA
			$V_{DET}=3.2-4.2V$	-	0.80	2.40	
			$V_{DET}=4.3-5.2V$	-	0.85	2.55	
			$V_{DET}=5.3-6.0V$	-	0.90	2.70	
Operating Voltage Range	V_{OPL}	$V_{OL} \leq 0.4V, T_a=25$ to $105^{\circ}\text{C}, R_L=470k\Omega$		0.95	-	-	V
		$V_{OL} \leq 0.4V, T_a=-40$ to $25^{\circ}\text{C}, R_L=470k\Omega$		1.20	-	-	
'Low' Output Voltage (Nch)	V_{OL}	$V_{DD}=1.5V, I_{SINK}=0.4\text{mA}, V_{DET}=2.3-6.0V$		-	-	0.5	V
		$V_{DD}=2.4V, I_{SINK}=2.0\text{mA}, V_{DET}=2.7-6.0V$		-	-	0.5	
'High' Output Voltage (Pch)	V_{OH}	$V_{DD}=4.8V, I_{SOURCE}=0.7\text{mA}, V_{DET}(2.3V \text{ to } 4.2V)$		$V_{DD}-0.5$	-	-	V
		$V_{DD}=6.0V, I_{SOURCE}=0.9\text{mA}, V_{DET}(4.3V \text{ to } 5.2V)$		$V_{DD}-0.5$	-	-	
		$V_{DD}=8.0V, I_{SOURCE}=1.1\text{mA}, V_{DET}(5.3V \text{ to } 6.0V)$		$V_{DD}-0.5$	-	-	

 $V_{DET}(T)$: Standard Detection Voltage (2.3V to 6.0V, 0.1V step) R_L : Pull-up resistor to be connected between V_{OUT} and power supply.
Design Guarantee. (Outgoing inspection is not done on all products.)*1 Guarantee is at $T_a=25^{\circ}\text{C}$.

●Electrical characteristics (Unless Otherwise Specified Ta=-40 to 105°C) - continued

Parameter	Symbol	Condition	Limit			Unit
			Min.	Typ.	Max.	
Leak Current when OFF	I_{leak}	$V_{DD}=V_{DS}=10V$ *1	-	-	0.1	μA
C_T pin Threshold Voltage	V_{CTH}	$V_{DD}=V_{DET}\times 1.1$, $V_{DET}=2.3-2.6V$, $R_L=470k\Omega$	$V_{DD}\times 0.30$	$V_{DD}\times 0.40$	$V_{DD}\times 0.60$	V
		$V_{DD}=V_{DET}\times 1.1$, $V_{DET}=2.7-4.2V$, $R_L=470k\Omega$	$V_{DD}\times 0.30$	$V_{DD}\times 0.45$	$V_{DD}\times 0.60$	
		$V_{DD}=V_{DET}\times 1.1$, $V_{DET}=4.3-5.2V$, $R_L=470k\Omega$	$V_{DD}\times 0.35$	$V_{DD}\times 0.50$	$V_{DD}\times 0.60$	
		$V_{DD}=V_{DET}\times 1.1$, $V_{DET}=5.3-6.0V$, $R_L=470k\Omega$	$V_{DD}\times 0.40$	$V_{DD}\times 0.50$	$V_{DD}\times 0.60$	
Output Delay Resistance	R_{CT}	$V_{DD}=V_{DET}\times 1.1$ $V_{CT}=0.5V$ *1	5.5	9	12.5	$M\Omega$
C_T pin Output Current	I_{CT}	$V_{CT}=0.1V$ $V_{DD}=0.95V$ *1	15	40	-	μA
		$V_{CT}=0.5V$ $V_{DD}=1.5V$	150	240	-	
Detection Voltage Temperature coefficient	$V_{DET}/\Delta T$	Ta=-40°C to 105°C	-	± 100	± 360	ppm/°C
Hysteresis Voltage	ΔV_{DET}	$V_{DD}=L\rightarrow H\rightarrow L$, $R_L=470k\Omega$	$V_{DET}\times 0.03$	$V_{DET}\times 0.05$	$V_{DET}\times 0.08$	V

$V_{DET}(T)$: Standard Detection Voltage (2.3V to 6.0V, 0.1V step)

R_L : Pull-up resistor to be connected between V_{OUT} and power supply.
Design Guarantee. (Outgoing inspection is not done on all products.)

*1 Guarantee is at Ta=25°C.

●Block Diagrams

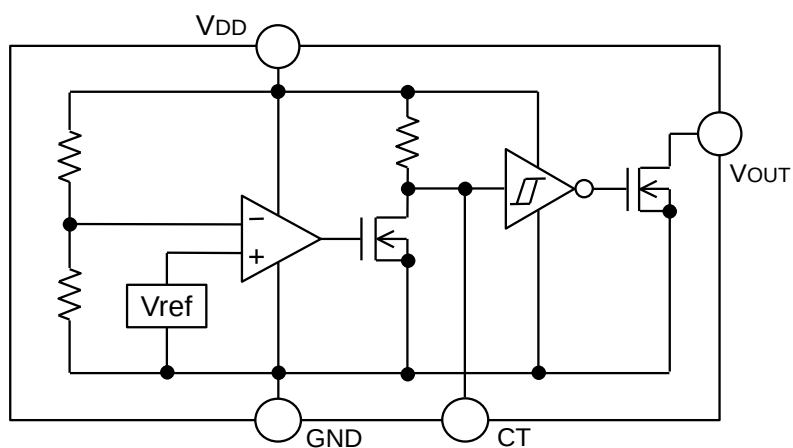


Figure.1 BD52Exxx-M Series

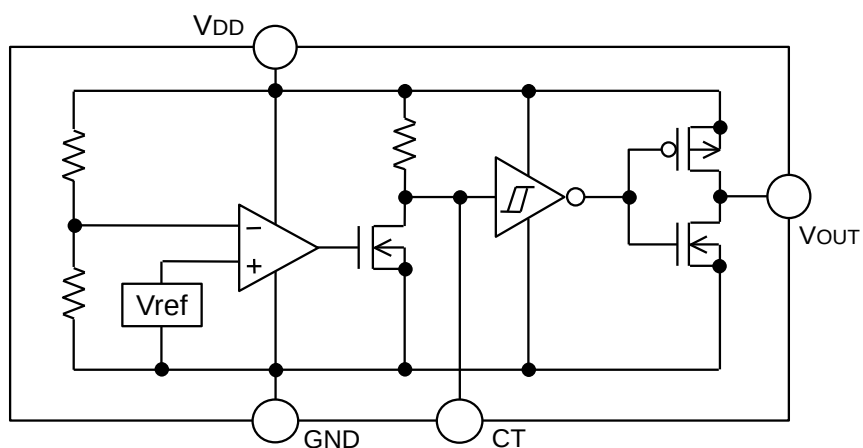


Figure.2 BD53Exxx-M Series

● Typical Performance Curves

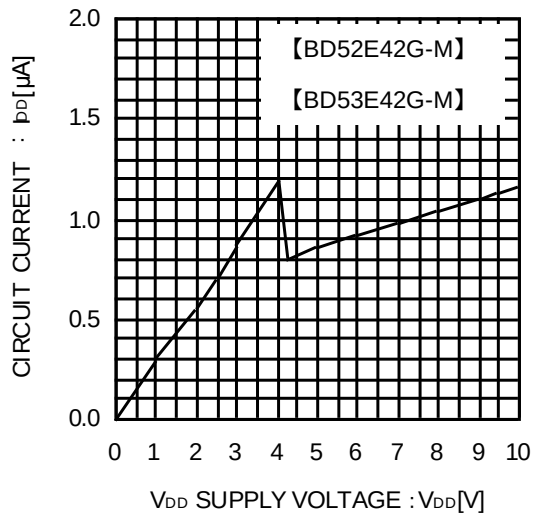


Figure.3 Circuit Current

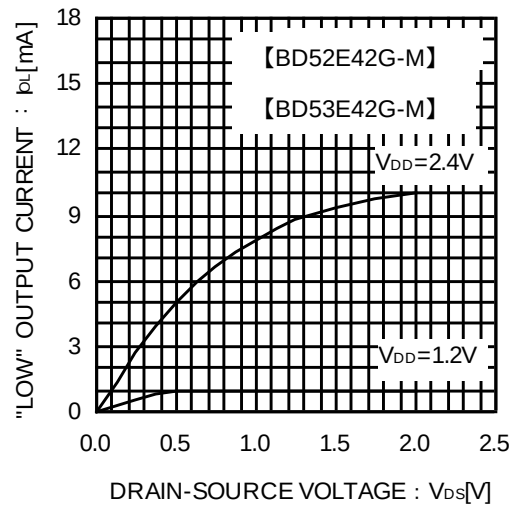


Figure.4 "Low" Output Current

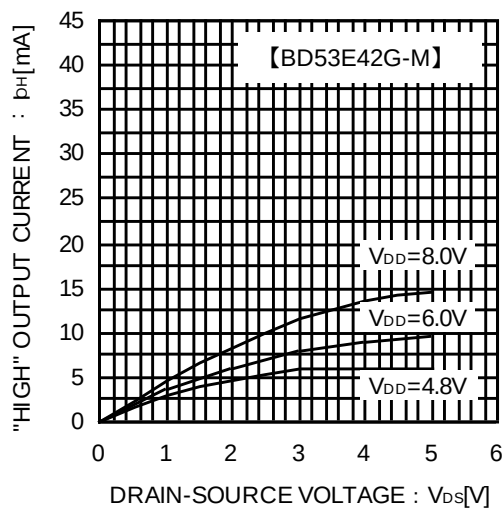


Figure.5 "High" Output Current

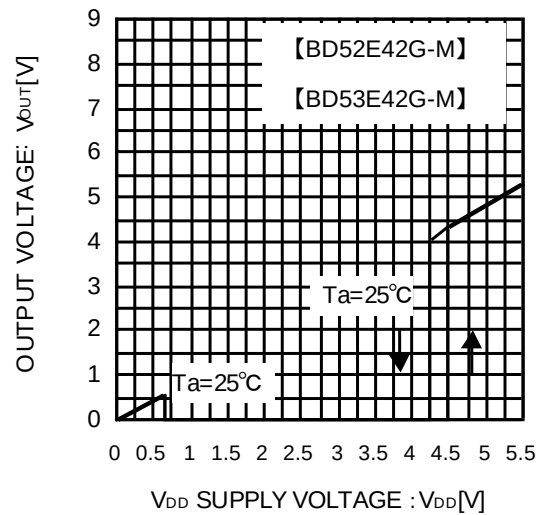


Figure.6 I/O Characteristics

●Typical Performance Curves – continued

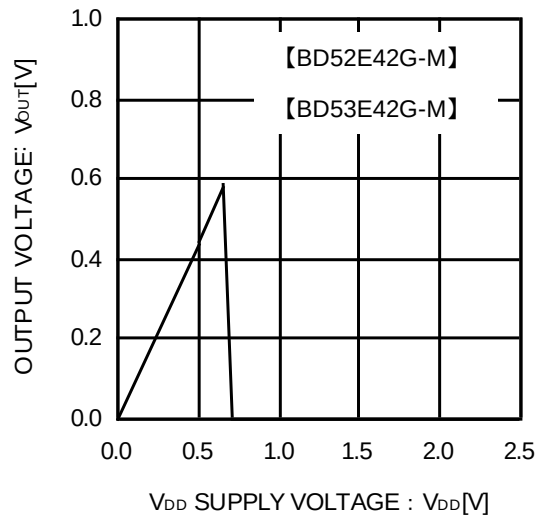


Figure.7 Operating Limit Voltage

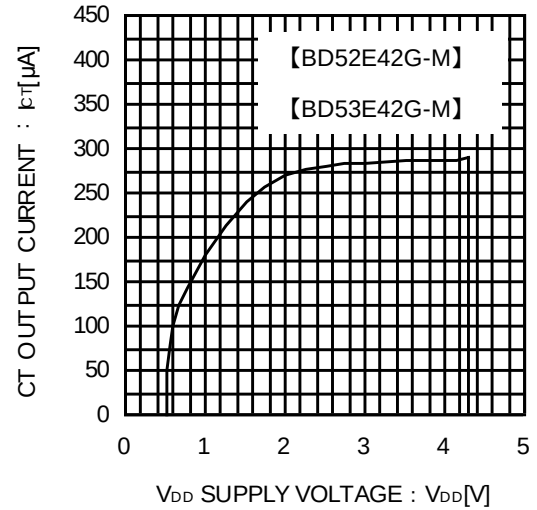


Figure.8 CT Terminal Current

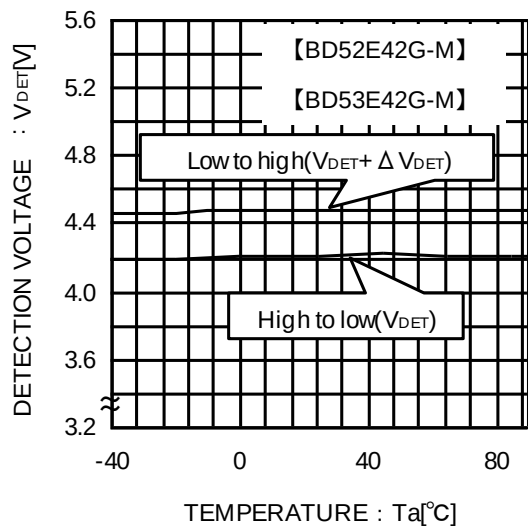


Figure.9 Detection Voltage Release Voltage

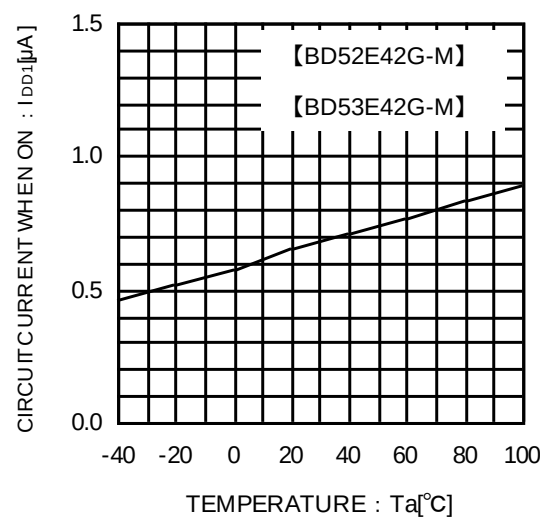


Figure.10 Circuit Current when ON

●Typical Performance Curves – continued

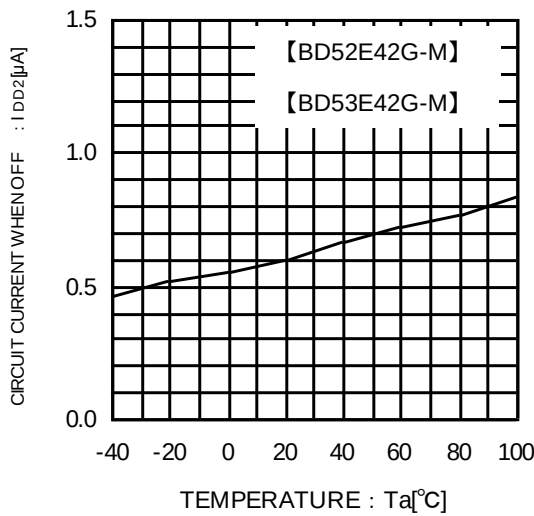


Figure.11 Circuit Current when OFF

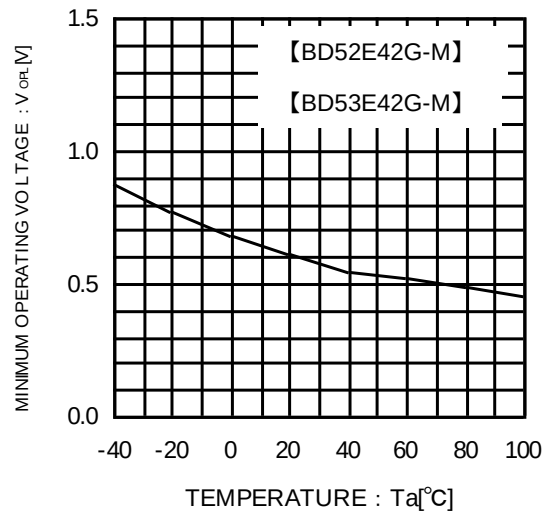


Figure.12 Operating Limit Voltage

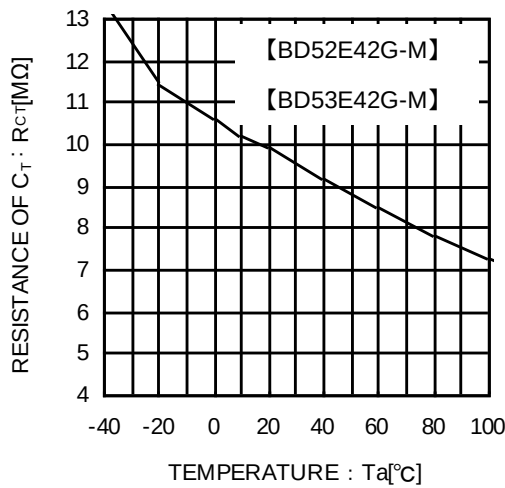


Figure.13 C_T Terminal Circuit Resistance

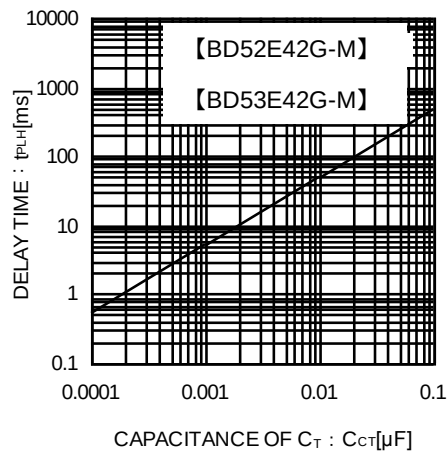


Figure.14 Delay Time (t_{PLH}) and C_T Terminal External Capacitance

● Application Information

Explanation of Operation

For both the open drain type (Figure.15) and the CMOS output type (Figure.16), the detection and release voltages are used as threshold voltages. When the voltage applied to the V_{DD} pins reaches the applicable threshold voltage, the V_{OUT} terminal voltage switches from either “High” to “Low” or from “Low” to “High”. Please refer to the Timing Waveform and Electrical Characteristics for information on hysteresis. Because the BD52Exxx-M series uses an open drain output type, it is necessary to connect a pull-up resistor to V_{DD} or another power supply if needed [The output “High” voltage (V_{OUT}) in this case becomes V_{DD} or the voltage of the other power supply].

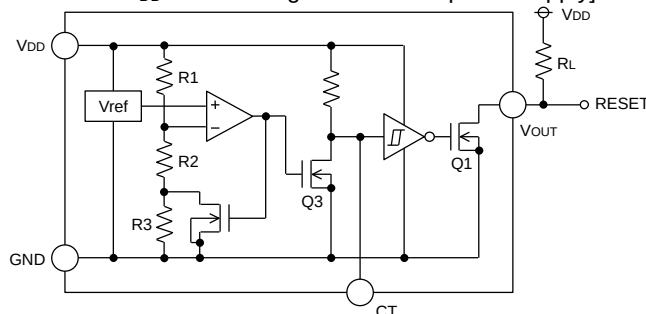


Figure.15 (BD52Exxx-M Type Internal Block Diagram)

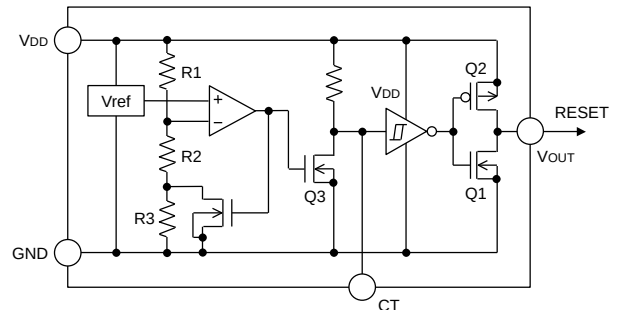


Figure.16 (BD53Exxx-M Type Internal Block Diagram)

Setting of Detector Delay Time

It is possible to set the delay time at the rise of V_{DD} using a capacitor connected to the C_T terminal.

Delay time at the rise of V_{DD} t_{PLH} : Time until when V_{out} rise to 1/2 of V_{DD} after V_{DD} rise up and beyond the release voltage ($V_{DET} + \Delta V_{DET}$)

$$t_{PLH} = -C_{CT} \times R_{CT} \times \ln \left(\frac{V_{DD} - V_{CTH}}{V_{DD}} \right)$$

C_{CT} : C_T pin Externally Attached Capacitance

R_{CT} : C_T pin Internal Impedance (Please refer to Electrical Characteristics.)

V_{CTH} : C_T pin Threshold Voltage (Please refer to Electrical Characteristics.)

$\ln$: Natural Logarithm

Reference Data of Falling Time (t_{PHL}) Output

Examples of Falling Time (t_{PHL}) Output

Part Number	$t_{PHL}[\mu s]$ -40°C	$t_{PHL}[\mu s]$,+25°C	$t_{PHL}[\mu s]$,+105°C
BD52E27G-M	30.8	30	28.8
BD53E27G-M	26.8	26	24.8

*This data is for reference only.

The figures will vary with the application, so confirm actual operating conditions before use.

Timing Waveforms

Example: the following shows the relationship between the input voltage V_{DD} , the C_T Terminal Voltage V_{CT} and the output voltage V_{OUT} when the input power supply voltage V_{DD} is made to sweep up and sweep down (The circuits are those in Figure.15 and 16).

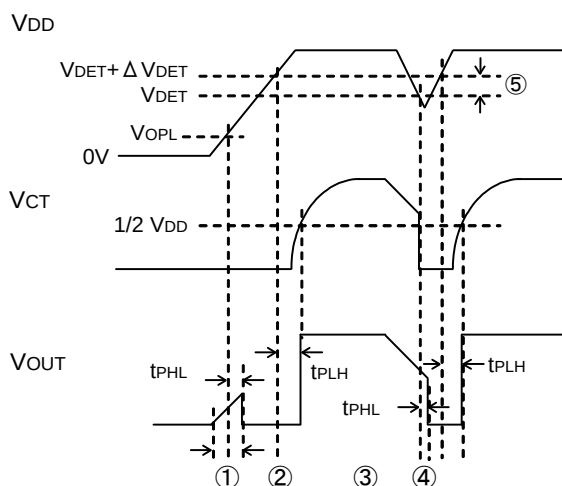


Figure.17 Timing Waveform

① When the power supply is turned on, the output is unstable from after over the operating limit voltage (V_{OPL}) until t_{PHL} . Therefore it is possible that the reset signal is not outputted when the rise time of V_{DD} is faster than t_{PHL} .

② When V_{DD} is greater than V_{OPL} but less than the reset release voltage ($V_{DET} + \Delta V_{DET}$), the C_T terminal (V_{CT}) and output (V_{OUT}) voltages will switch to L.

③ If V_{DD} exceeds the reset release voltage ($V_{DET} + \Delta V_{DET}$), then V_{OUT} switches from L to H (with a delay due to the C_T terminal).

④ If V_{DD} drops below the detection voltage (V_{DET}) when the power supply is powered down or when there is a power supply fluctuation, V_{OUT} switches to L (with a delay of t_{PHL}).

⑤ The potential difference between the detection voltage and the release voltage is known as the hysteresis width (ΔV_{DET}). The system is designed such that the output does not toggle with power supply fluctuations within this hysteresis width, preventing malfunctions due to noise.

● Circuit Applications

1) Examples of a common power supply detection reset circuit

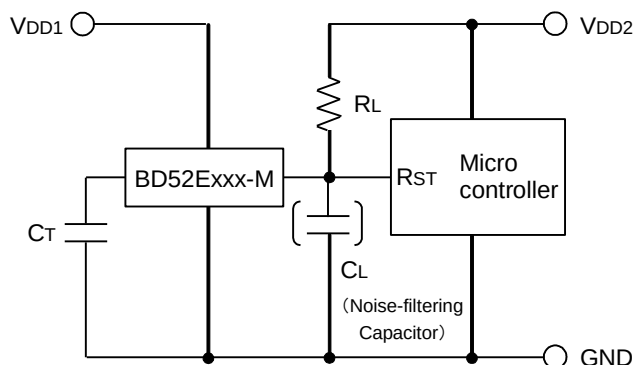


Figure.18 Open Drain Output Type

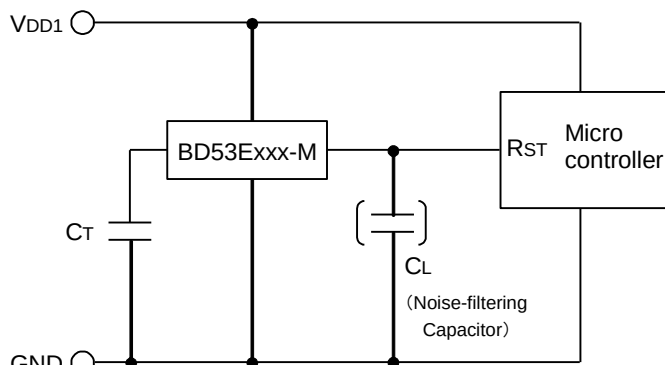


Figure.19 CMOS Output Type

Application examples of BD52Exxx series (Open Drain output type) and BD53Exxx series (CMOS output type) are shown below.

CASE1: Power supply of the microcontroller (V_{DD2}) differs from the power supply of the reset detection (V_{DD1}).

Use an open drain output type (BD52Exxx) with a load resistance R_L attached as shown Figure.18.

CASE2: Power supply of the microcontroller (V_{DD1}) is the same as the power supply of the reset detection (V_{DD1}).

Use a CMOS output type (BD53Exxx) device or open drain output type (BD52Exxx) device with a pull up resistor attached between the output and V_{DD1} .

When a capacitance C_L for noise filtering is connected to the V_{OUT} pin (the reset signal input terminal of the microcontroller), please take into account the waveform of the rise and fall of the output voltage (V_{OUT}).

Please refer to Operational Notes for recommendations on resistor and capacitor values.

2) The following is an example of a circuit application in which an OR connection between two types of detection voltage resets the microcontroller.

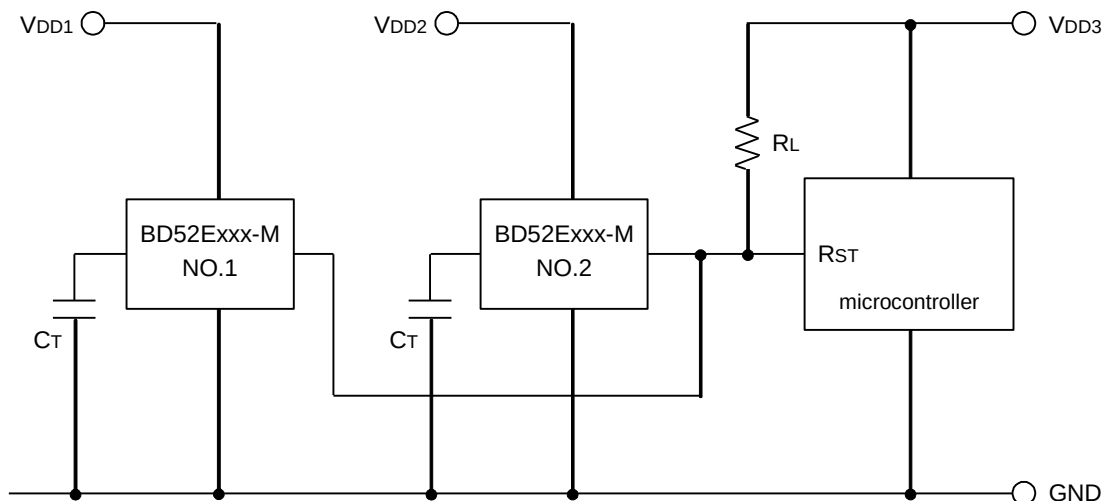
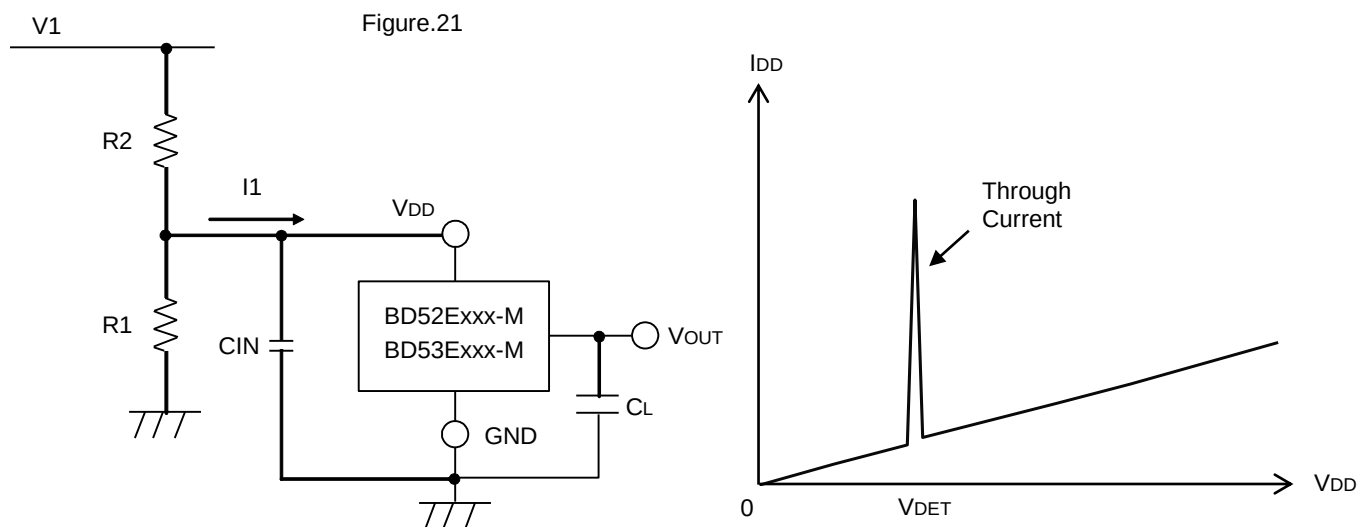


Fig.20

To reset the microcontroller when many independent power supplies are used in the system, OR connect an open drain output type (BD52Exxx-M series) to the microcontroller's input with pull-up resistor to the supply voltage of the microcontroller (V_{DD3}) as shown in Fig. 20. By pulling-up to V_{DD3} , output "High" voltage of micro-controller power supply is possible.

3) Examples of the power supply with resistor dividers

In applications wherein the power supply voltage of an IC comes from a resistor divider circuit, an in-rush current will flow into the circuit when the output level switches from "High" to "Low" or vice versa. In-rush current is a sudden surge of current that flows from the power supply (VDD) to ground (GND) as the output logic changes its state. This current flow may cause malfunction in the systems operation such as output oscillations, etc.



When an in-rush current (I_1) flows into the circuit (Refer to Fig. 21) at the time when output switches from "Low" to "High", a voltage drop of $I_1 \times R_2$ (input resistor) will occur in the circuit causing the VDD supply voltage to decrease. When the VDD voltage drops below the detection voltage, the output will switch from "High" to "Low". While the output voltage is at "Low" condition, in-rush current will stop flowing and the voltage drop will be reduced. As a result, the output voltage will switch again from "Low" to "High" which causes an in-rush current and a voltage drop. This operation repeats and will result to oscillation.

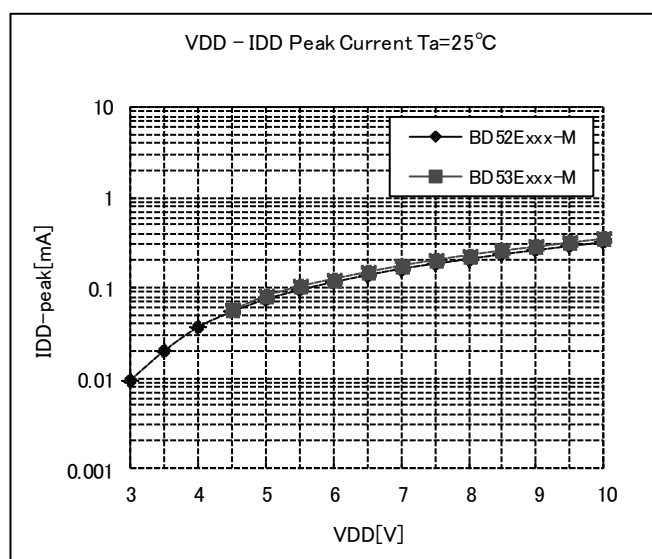


Figure.22 IDD Peak Current vs. Power Supply Voltage

* This data is for reference only.

The figures will vary with the application, so please confirm actual operating conditions before use.

●Operational Notes

- 1) Absolute maximum ratings
Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.
- 2) Ground Voltage
The voltage of the ground pin must be the lowest voltage of all pins of the IC at all operating conditions. Ensure that no pins are at a voltage below the ground pin at any time, even during transient condition.
- 3) Recommended operating conditions
These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.
- 4) Bypass Capacitor for Noise Rejection
To help reject noise, put a 1 μ F capacitor between V_{DD} pin and GND and 1000pF capacitor between V_{OUT} pin and GND. Be careful when using extremely big capacitor as transient response will be affected.
- 5) Short between pins and mounting errors
Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.
- 6) Operation under strong electromagnetic field
Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.
- 7) The V_{DD} line impedance might cause oscillation because of the detection current.
- 8) A V_{DD} to GND capacitor (as close connection as possible) should be used in high V_{DD} line impedance condition.
- 9) Lower than the minimum input voltage puts the V_{OUT} in high impedance state, and it must be V_{DD} in pull up (V_{DD}) condition.
- 10) External parameters
The recommended value of R_L Resistor is 50k Ω to 1M Ω . The recommended value of C_T Capacitor is over 100pF to 0.1 μ F. There are many factors (board layout, etc) that can affect characteristics. Please verify and confirm using practical applications.
- 11) Power on reset operation
Please note that the power on reset output varies with the V_{DD} rise time. Please verify the behavior in the actual operation.
- 12) Testing on application boards
When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.
- 13) Rush current
When power is first supplied to the IC, rush current may flow instantaneously. It is possible that the charge current to the parasitic capacitance of internal photo diode or the internal logic may be unstable. Therefore, give special consideration to power coupling capacitance, power wiring, width of GND wiring, and routing of connections.
- 14) C_T pin discharge
Due to the capabilities of the C_T pin discharge transistor, the C_T pin may not completely discharge when a short input pulse is applied, and in this case the delay time may not be controlled. Please verify the actual operation.

Notice

Precaution on using ROHM Products

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
4. The Products are not subject to radiation-proof design.
5. Please verify and confirm characteristics of the final or mounted products in using the Products.
6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
8. Confirm that operation temperature is within the specified range described in the product specification.
9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

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